Finite-temperature phase diagram of nonmagnetic impurities in high-temperature superconductors using a d = 3 tJ model with quenched disorder

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We study a quenched disordered d=3 tJ Hamiltonian with static vacancies as a model of nonmagnetic impurities in high- T_c materials. Using a renormalization-group approach, we calculate the evolution of the finite-temperature phase diagram with impurity concentration p, and find several features with close experimental parallels: away from half-filling we see the rapid destruction of a spin-singlet phase (analogous to the superconducting phase in cuprates) which is eliminated for $p \gtrsim 0.05$; in the same region for these dilute impurity concentrations we observe an enhancement of antiferromagnetism. The antiferromagnetic phase near half-filling is robust against impurity addition, and disappears only for $p \gtrsim 0.40$.

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The electronic properties and phase diagram of high- T_c materials are particularly sensitivity to impuritiessubstitution of 3d transition elements (Zn, Ni, Co, Fe), or other metals (Al, Ga), for the Cu atoms of the CuO₂ planes [1]. The interplay between disorder, strong antiferromagnetic correlations in the parent compound, and doped charge carriers, offers a window onto the nature of both the superconducting phase and the normal state above T_c . Doping by nonmagnetic (S=0) Zn ions provides one representative example: the most pronounced effect is the rapid destruction of the superconducting phase [1, 2]; in YBCO the transition temperature is reduced at a rate of $\sim 15 \text{K/at.}\%$ of impurities, so that it takes Zn concentrations of only about 6% to entirely eliminate superconductivity [2]. This is in contrast to the antiferromagnetic phase at half-filling, which requires a far larger Zn concentration (about 40% in LSCO [3]) to completely suppress. The effects in the metallic region above T_c are equally surprising: nuclear magnetic resonance experiments have found that Zn atoms induce local magnetic moments at nearest-neighbor Cu sites [4], and enhance antiferromagnetic correlations for several lattice spacings around the impurity [5, 6]. In lightly hole-doped LSCO there have been observations of an initial increase in the Néel temperature with Zn addition, and even impurity-induced reappearance of long-range antiferromagnetic order [7, 8].

In this work we model the effects of nonmagnetic impurities in high- T_c materials through a $d=3\ tJ$ Hamiltonian with quenched disorder in the form of static vacancies. Through a renormalization-group (RG) approach we obtain the evolution of the global temperature versus chemical potential phase diagram with disorder. Our results capture in a single microscopic model some of the major qualitative features of impurity-doping in real materials: the rapid suppression of a spin-singlet phase, analogous to the superconducting phase in cuprates; the gradual reduction of the antiferromagnetic phase near half-filling; and the enhancement of antiferromagnetism away from half-filling for small impurity concentrations.

We consider the quenched disordered tJ model on a d-dimensional hypercubic lattice, $-\beta H = \sum_{\langle ij \rangle} \{-\beta H_0(i,j)\} + \sum_i \mu_i^{\text{imp}} n_i$, where $-\beta H_0(i,j) = -t \sum_{\sigma} (c_{i\sigma}^{\dagger} c_{j\sigma} + c_{j\sigma}^{\dagger} c_{i\sigma}) - J(\mathbf{S}_i \cdot \mathbf{S}_j - n_i n_j / 4) + \mu(n_i + n_j)$ is the standard tJ model pair Hamiltonian. The static impurities at each site i occur with probability p via $\mu_i^{\text{imp}} = -\infty$ and do not occur with probability 1 - p via $\mu_i^{\text{imp}} = 0$.

To formulate an RG transformation for this system, we use the d=1 Suzuki-Takano decimation [9–19], generalized to d>1 through the Migdal-Kadanoff method [20, 21]. This technique, adapted for quenched random bond disorder, has recently elucidated the phase diagrams of the quantum Heisenberg spin-glass in various spatial dimensions [18]. In our case the rescaling for the d=1 system (with sites $i=1,2,3,\ldots$) is:

$$\begin{aligned} &\operatorname{Tr}_{\operatorname{even}} e^{-\beta H} \\ &= \operatorname{Tr}_{\operatorname{even}} e^{\sum_{i} \left\{-\beta H_{0}(i,i+1) + \mu_{i}^{\operatorname{imp}} n_{i}\right\}} \\ &= \operatorname{Tr}_{\operatorname{even}} e^{\sum_{i}^{\operatorname{even}} \left\{-\beta H_{0}(i-1,i) + \mu_{i}^{\operatorname{imp}} n_{i} - \beta H_{0}(i,i+1)\right\} + \sum_{i}^{\operatorname{odd}} \mu_{i}^{\operatorname{imp}} n_{i}} \\ &\simeq \left[\prod_{i}^{\operatorname{even}} \operatorname{Tr}_{i} e^{-\beta H_{0}(i-1,i) + \mu_{i}^{\operatorname{imp}} n_{i} - \beta H_{0}(i,i+1)}\right] e^{\sum_{i}^{\operatorname{odd}} \mu_{i}^{\operatorname{imp}} n_{i}} \\ &= \left[\prod_{i}^{\operatorname{even}} e^{-\beta' H'_{0}(i-1,i+1)}\right] e^{\sum_{i}^{\operatorname{odd}} \mu_{i}^{\operatorname{imp}} n_{i}} \\ &\simeq e^{\sum_{i}^{\operatorname{even}} \left\{-\beta' H'_{0}(i-1,i+1) + \mu_{i-1}^{\operatorname{imp}} n_{i-1}\right\}} = e^{-\beta' H'}, \end{aligned} \tag{1}$$

where the traces and sums are over even- or oddnumbered sites i, and $-\beta'H'$ is the renormalized Hamiltonian. Anticommutation rules are correctly accounted for within segments of three consecutive sites, at all successive length scales as the RG transformation is iterated.

The algebraic content of the RG transformation is contained in the second and third lines of Eq. (1), yielding the renormalized pair Hamiltonian $-\beta' H'_0(i',j')$ through the relation: $\exp(-\beta' H'_0(i',j')) = \operatorname{Tr}_k \exp(-\beta H_0(i',k) + \mu_k^{\text{imp}} n_k - \beta H_0(k,j'))$. Under the transformation the original system is mapped onto one with a more

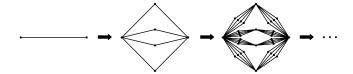


FIG. 1: Hierarchical lattice on which the $d=3,\,b=2$ Migdal-Kadanoff recursion relations are exact.

general form of the pair Hamiltonian, $-\beta H_0(i,j) =$ $-t_{ij} \sum_{\sigma} (c_{i\sigma}^{\dagger} c_{j\sigma} + c_{j\sigma}^{\dagger} c_{i\sigma}) - J_{ij} \mathbf{S}_{i} \cdot \mathbf{S}_{j} + V_{ij} n_{i} n_{j} + \mu_{ij} (n_{i} + n_{j}) + \nu_{ij} (n_{i} - n_{j}) + G_{ij}, \text{ where the interaction con-}$ stants $\mathbf{K}_{ij} \equiv (t_{ij}, J_{ij}, V_{ij}, \mu_{ij}, \nu_{ij})$ are nonuniform, and distributed with a joint quenched probability distribution $\mathcal{P}(\mathbf{K}_{ij})$. This generalized form of the Hamiltonian remains closed under further RG transformations. Through the relation above we can write the interaction constants $\mathbf{K}'_{i'i'}$ of the renormalized pair Hamiltonian $-\beta' H'_0(i',j')$ as a function of the interaction constants $\mathbf{K}_{i',k}$ and $\mathbf{K}_{k,j'}$ of two consecutive nearestneighbor pairs in the unrenormalized system, $\mathbf{K}'_{i'i'}$ = $\mathbf{R}(\mathbf{K}_{i'k},\mathbf{K}_{ki'}).$ This function \mathbf{R} comes in two varieties, depending on whether or not there is an impurity at site k, which we shall denote as \mathbf{R}_0 and \mathbf{R}_{imp} respectively. Starting with a system with quenched probability distribution $\mathcal{P}(\mathbf{K}_{ij})$, the distribution $\mathcal{P}'(\mathbf{K}'_{i'i'})$ of the renormalized system is given by the decimation convolution [22]: $\mathcal{P}'(\mathbf{K}'_{i'j'}) = \int d\mathbf{K}_{i'k} d\mathbf{K}_{kj'} \, \mathcal{P}(\mathbf{K}_{i'k}) \mathcal{P}(\mathbf{K}_{kj'}) [p\delta(\mathbf{K}'_{i'j'} \mathbf{R}_{\text{imp}}(\mathbf{K}_{i'k}, \mathbf{K}_{kj'})) + (1-p)\delta(\mathbf{K}'_{i'j'} - \mathbf{R}_0(\mathbf{K}_{i'k}, \mathbf{K}_{kj'}))].$ The initial condition for the RG flow is the distribution corresponding to the original system, $\mathcal{P}_0(\mathbf{K}_{ij}) = \delta(\mathbf{K}_{ij} - \mathbf{K}_0)$, where $\mathbf{K}_0 = \{t, J, -J/4, \mu, 0\}.$

The RG transformation is extended to d > 1 through the Migdal-Kadanoff [20, 21] procedure. While approximate for hypercubic lattices, the recursion relations generated by this procedure are exact on hierarchical lattices [23–25], and we shall use this correspondence to describe the RG transformation for the case d=3, with length rescaling factor b = 2. The associated hierarchical lattice is shown in Fig. 1. Its construction proceeds by taking each bond in the lattice, replacing it by the connected cluster of bonds in the middle of Fig. 1, and repeating this step an infinite number of times. The RG transformation consists of reversing this construction process, by taking every such cluster of bonds, decimating over the degrees of freedom at the four inner sites of the cluster, yielding a renormalized interaction between the two edge sites of the cluster. Denoting these edge sites as i', j', and the four inner sites as k_1, \ldots, k_4 , this decimation can be expressed as $\mathbf{K}_{i'j'} = \sum_{n=1}^4 \mathbf{R}(\mathbf{K}_{i'k_n}, \mathbf{K}_{k_nj'})$. Just as in the d=1 case, this decimation will give, after a single RG transformation, a system with a nonuniform quenched distribution of interaction constants. We can calculate the quenched probability distribution $\mathcal{P}'(\mathbf{K}_{i'i'})$ of the renormalized system through a series of pairwise convolutions, consisting of the decimation convolution

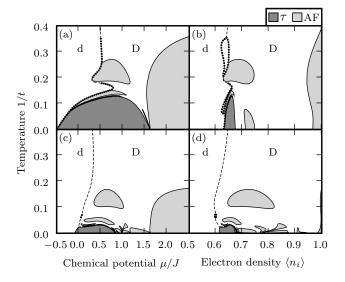


FIG. 2: Pure system (p=0) phase diagram of the isotropic d=3 tJ model [11, 12] for J/t=0.444: (a) in terms of chemical potential μ/J vs. temperature 1/t; (b) electron density $\langle n_i \rangle$ vs. temperature 1/t. Panels (c) and (d) show the analogous phase diagrams for the uniaxially anisotropic case [17], with $t_z/t_{xy}=0.3$, $J_z/J_{xy}=0.9$, $J_{xy}/t_{xy}=0.444$. In both cases antiferromagnetic (AF), dense disordered (D), dilute disordered (d), and τ phases are seen. The solid lines represent second-order phase transitions, while the dotted lines are first-order phase transitions (with the unmarked areas inside corresponding to coexistence regions of the two phases at either side). Dashed lines are not phase transitions, but disorder lines between the dilute disordered and dense disordered phases.

defined above for interactions in series, and a "bondmoving" convolution for interactions in parallel, using the function $\mathbf{R}_{bm}(\mathbf{K}_A, \mathbf{K}_B) = \mathbf{K}_A + \mathbf{K}_B$. In order to numerically implement the convolution, the probability distributions are represented by histograms, where each histogram is a set of interaction constants (t, J, V, μ, ν) and an associated probability. Since the number of histograms that constitute the probability distribution increases rapidly with each RG iteration, a binning procedure is used [26]. Furthermore since evaluation of the R functions is computationally expensive, and most of the weight of the probability distributions is carried by a fraction of the histograms, we have added an additional step before the decimation convolution to increase efficiency: the histograms with the 100 largest probabilities are left unchanged, while the others are collapsed into a single histogram in a way that preserves the average and standard deviation of the quenched distribution. Thus we evaluate 10⁴ local decimations at each RG transformation.

All thermodynamic properties of the system, in particular the finite-temperature phase diagram, can be determined from analyzing the RG flows. In the pure (p=0) case, the transformation described above reduces to the recursion relations derived for the $d=3\ tJ$ model in ear-

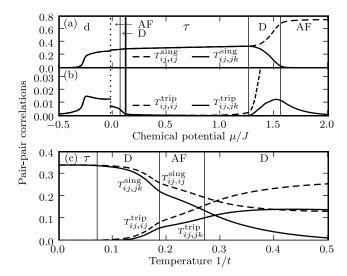


FIG. 3: On-site and nearest-neighbor singlet and triplet pairpair correlations for the d=3 tJ model, with p=0, J/t=0.444. In (a) and (b) the correlations are plotted as a function of chemical potential μ/J at constant temperature 1/t=0.10. In (c) they are plotted as a function of temperature 1/t, at the constant electron density $\langle n_i \rangle = 0.67$. The corresponding phases are indicated near the top of each plot, with solid and dotted vertical lines marking second-order and first-order phase boundaries respectively.

lier studies [11, 12], and yields the phase diagram shown in Fig. 2(a,b) for J/t=0.444. Here we summarize the observed phases (for details, consult [11, 12]): near half-filling $(\mu/J \to \infty, \langle n_i \rangle \to 1)$, there is a transition with decreasing temperature from a densely-filled disordered phase (D) to long-range antiferromagnetic order (AF). This AF phase persists away from half-filling down to $\mu/J \approx 1.6$, or 5% hole doping. For very large hole dopings ($\gtrsim 37\%$) we go over into a dilute disordered phase (d), with narrow first-order coexistence regions between the d and D phases. At intermediate hole dopings of 33-37% a novel phase (τ) is found at low temperatures, flanked by an intricate lamellar structure of AF islands.

The τ phase is characterized by the formation of nearest-neighbor spin-singlet pairs, as can be understood from correlation functions calculated using the RG flows. Let us define a singlet pair-pair correlation function $T_{ij,kl}^{\rm sing} = \langle \Delta_{ij}^{\rm sing}^{\dagger} \Delta_{kl}^{\rm sing}^{\dagger} + \Delta_{kl}^{\rm sing}^{\dagger} \Delta_{ij}^{\rm sing} \rangle$, where $\Delta_{ij}^{\rm sing} = \frac{1}{\sqrt{2}} (c_{i\downarrow}c_{j\uparrow} - c_{i\uparrow}c_{j\downarrow})$, and the analogous triplet correlation function $T_{ij,kl}^{\rm trip}$ in terms of $\Delta_{ij}^{\rm trip} = c_{i\uparrow}c_{j\uparrow} + \frac{1}{\sqrt{2}} (c_{i\downarrow}c_{j\uparrow} + c_{i\uparrow}c_{j\downarrow}) + c_{i\downarrow}c_{j\downarrow}$. For clusters of three consecutive sites i,j,k in the lattice, Fig. 3 shows the on-site correlations $T_{ij,ij}^{\rm sing}$, $T_{ij,ij}^{\rm trip}$, and nearest-neighbor correlations $T_{ij,jk}^{\rm sing}$, $T_{ij,ij}^{\rm trip}$. In Fig. 3(a) and (b), we see a constant temperature slice at 1/t = 0.10 as μ/J is varied. There is a broad region of chemical potentials away from half-filling, centered at the τ phase, where both the on-site and nearest-neighbor singlet correlations are strong, in contrast to the triplet correlations, which are suppressed

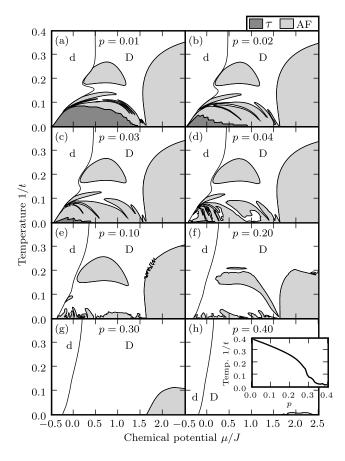


FIG. 4: Calculated phase diagrams of the d=3 tJ model, with J/t=0.444, for various values of the impurity concentration p, plotted in terms of temperature 1/t vs. chemical potential μ/J . The phases depicted in the figures are: dilute disordered (d), dense disordered (D), antiferromagnetic (AF), and τ . The inset shows AF transition temperatures for the near-half-filled system ($\mu/J=100$) as a function of p.

in the same region. We see similar behavior in Fig. 3(c), where the correlations are plotted as a function of temperature 1/t at a constant electron density $\langle n_i \rangle = 0.67$. As we decrease the temperature, approaching the transition into the τ phase, there is a significant increase in the singlet correlations and rapid decay of the triplet correlations. Spin-singlet liquids, i.e., the hole-doped resonating valence bond (RVB) state, have featured prominently in theories of high- T_c superconductivity (for a review see Ref. [27]). As we shall see below, the behavior of the τ phase under impurity-doping is analogous to that of the superconducting phase in high- T_c materials.

Though in this study we focus on the isotropic d=3 model, there is evidence that general features of the p=0 phase diagram discussed above persist even in the case of spatial anisotropy, with uniform interactions (t_{xy}, J_{xy}) along the xy planes and weaker interactions (t_z, J_z) along the z direction. Through a similar RG approach, using the more complicated hierarchical lattice associated with a uniaxially anisotropic cubic lattice [28], it was found in particular that the τ phase con-

tinues to exist in roughly the same doping range even for weak interplanar coupling, though as expected the transition temperatures steadily decrease as the coupling is reduced [17]. A representative phase diagram, with $t_z/t_{xy}=0.3$, $J_z/J_{xy}=0.09$, $J_{xy}/t_{xy}=0.444$, is shown in Fig. 2(c,d). Thus the τ phase may be relevant even in the strongly anisotropic regime important for high- T_c materials, which are characterized by weakly interacting CuO₂ planes.

In Fig. 4 we show the evolution of our calculated phase diagram with increasing impurity concentration p. The τ phase is rapidly suppressed for p = 0.01 through 0.04 [Fig. 4(a)-(d)], and is no longer present by p = 0.05. The rate at which the τ phase disappears is comparable to the reduction of T_c with nonmagnetic impurities in cuprates, where typically concentrations $\approx 2-6\%$ (depending on dopant) are enough to eliminate superconductivity [1, 2]. As the area of the τ phase recedes for these small impurity concentrations, the region it formerly occupied is replaced by a complex lamellar structure of the AF phase. We can understand this enhancement of antiferromagnetism through an RVB-like picture of the τ phase [29]: in the pure case the nearest-neighbor singlets resonate in all possible arrangements along the bonds; when an impurity is added some of these arrangements are "pruned", because the bonds adjacent to the impurity can no longer accommodate singlets. This inhibition of singlet fluctuations leads to enhanced antiferromagnetic correlations around the vacancy. Such local AF enhancement near dilute nonmagnetic impurities has been observed through NMR and NQR studies on Zn-doped YBCO [5, 30], and supported theoretically by finite-cluster studies of the d=2 Heisenberg [31] and tJ[32, 33] models. More dramatically, in lightly hole-doped $\text{La}_{2-x}\text{Sr}_x\text{Cu}_{1-z}\text{Zn}_z\text{O}_4$ (with x=0.017) the Néel temperature actually increases with the addition of Zn up to z = 0.05, before turning downwards again at higher z [7]. A similar, though smaller, effect has been found even at larger hole dopings of x = 0.115 and 0.13, with the T_N increasing up to z = 0.0075 [8]. In the case of x = 0.13, there is even no long-range antiferromagnetic order for the Cu spins in the Zn-free compound; it appears for z > 0.0025. This reappearance of long-range AF order upon addition of impurities, at small hole-dopings away from half-filling where it does not exist in the pure case, was replicated in the $d=2\ tJ$ model using a self-consistent diagrammatic approach [34], and in the d=2 Hubbard model with the dynamical cluster approximation [35]. Thus the enhancement of the AF phase away from half-filling, which we find at small impurity concentrations, is consistent with previous experimental and theoretical indications.

On the other hand for larger concentrations of impurities, the dilution of the spins in the lattice becomes the dominant effect, and eventually all long-range magnetic order is destroyed in the system. We see this in Fig. 4(e)-(h), showing phase diagrams for p=0.10 through 0.40, and in the inset which plots the AF transition temperature as a function of p near half-filling ($\mu/J=100$). In contrast to the τ phase, the AF phase around half-filling is robust against impurity addition, and only disappears for $p\gtrsim 0.40$. Qualitatively similar behavior has been seen in the half-filled compound $\text{La}_2\text{Cu}_{1-z}\text{Zn}_z\text{O}_4$, where Zn concentrations of $z\approx 0.4$ are required to reduce the Néel temperature to zero [3], much larger than those needed to eliminate superconductivity in the hole-doped material.

To summarize, we have applied an RG approach to the quenched disordered d = 3 tJ model, and found the evolution of the phase diagram as a function of impurity concentration. The spin-singlet phase away from half-filling is quickly destroyed through the addition of small quantities of static vacancies, while antiferromagnetism in the same region is enhanced. The antiferromagnetic phase near half-filling is less sensitive to impurity addition, and completely disappears only at larger concentrations. These results all have close parallels in experimental results from cuprates. The RG method described here for dealing with quenched disorder in the tJHamiltonian could be generalized to more complex systems: for example the disordered Hubbard model, where the double-occupation of sites is allowed through a finite electron-electron repulsion. The role of electron correlations and disorder in this system has led to interesting phase diagram predictions [36–38], which could be further explored with RG techniques.

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